TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOSIV)

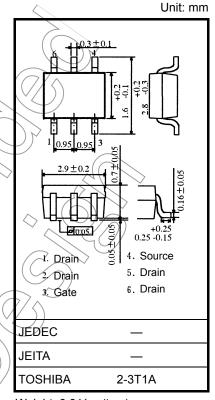
TPC6108

Notebook PC Applications Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: $R_{DS (ON)} = 50 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: |Yfs| = 7.4 S (typ.)
- Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -30 \text{ V)}$
- Enhancement mode: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_D = -1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | | Symbol | Rating | Upit |
|--|-------|----------|--------------------|---------------|------------|
| Drain-source voltage | | | V_{DSS} | -30 | \bigvee |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | | V_{DGR} | _30(| y |
| Gate-source voltage | | | V_{GSS} | ±20 | > v |
| Drain current | DC | (Note 1) | I _D | -4.5 | А |
| | Pulse | (Note 1) | I _{DP} | -18 | A |
| Drain power dissipation (t = 5 s) (Note 2a) | | | Pp | 2.2 | W |
| Drain power dissipation (t = 5 s) (Note 2b) | | | PD | 0.7 | < ~ |
| Single-pulse avalanche energy (Note 3) | | | (E _{AS}) | 1.3 | mJ |
| Avalanche current | | | 1AR | -2.25 | Α |
| Repetitive avalanche energy Single-device value at dual operation (Note 4) | | | EAR | 0.22 | /mJ |
| Channel temperature | | | T _{ch} | 150 | °C |
| Storage temperature range | | | T _{stg} | -55 to 150 | °C |
| * | 1 1 | | | \ \ \ / / / / | |



Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

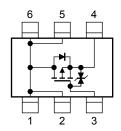
Thermal Characteristics

| | V | | |
|--|------------------------|-------|------|
| Characteristics | Symbol | Max | Unit |
| Thermal resistance, channel to ambient (t = 5 s) (Note 2a) | R _{th (ch-a)} | 56.8 | °C/W |
| Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2b) | R _{th (ch-a)} | 178.5 | °C/W |

Note: For Notes 1 to 4, see page 3.

Caution: This transistor is an electrostatic-sensitive device. Handle with care.

Circuit Configuration



Electrical Characteristics (Ta = 25°C)

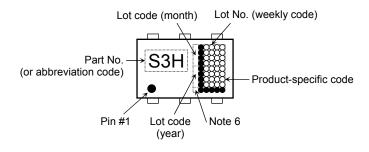
| Characteristic | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------|----------------------|---|--------|------|----------|------|
| Gate leakage current | | I _{GSS} | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μΑ |
| Drain cut-off current | | I _{DSS} | $V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$ | _ | _ | -10 | μΑ |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -30 | _ | _ | V |
| | | V (BR) DSX | $I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$ | 15 | _ | _ | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$ | (+0.8) | 7 | -2.0 | V |
| Drain-source ON-resistance | | R _{DS} (ON) | $V_{GS} = -4.5 \text{ V}, I_D = -2.2 \text{ A}$ | | 75 | 100 | - mΩ |
| | | R _{DS} (ON) | $V_{GS} = -10 \text{ V}, I_D = -2.2 \text{ A}$ | / A | 50 | 60 | |
| Forward transfer admittance | | Y _{fs} | $V_{DS} = -10 \text{ V}, I_D = -2.2 \text{ A}$ | 3.7 | 7.4 | _ | S |
| Input capacitance | | C _{iss} | | _ | 570 | | |
| Reverse transfer capacitance | | C _{rss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | _ | 75 | | pF |
| Output capacitance | | Coss | | _ | 85 | _ | |
| Switching time | Rise time | t _r | V _{GS} 0 V | - (| 3.5 | > > | — ns |
| | Turn-on time | t _{on} | VGS _10 V VOUT CI SE | | 12 |) — | |
| | Fall time | t _f | V _{DD} ≈ -15 V | 7 | > 21 | _ | |
| | Turn-off time | t _{off} | Duty \leq 1%, $t_W = 10 \mu s$ | | 70 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | V _{DD} ≈ -24 V, V _G ≈ -10 V, |) _ | 13 | | |
| Gate-source charge1 | | Q _{gs1} | I _D = -4.5 A | _ | 1.8 | _ | nC |
| Gate-drain ("Miller") charge | | Q _{gd} | · | _ | 2.5 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristic | Test Condition | Min | Тур. | Max | Unit |
|---|--|-----|------|-----|------|
| Drain reverse current Pulse (Note 1) I _{DRP} | (7/\ - | _ | _ | -18 | Α |
| Forward voltage (diode) V _{DSF} | $I_{DR} = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | 1.2 | V |



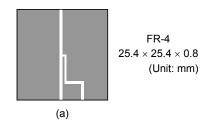
Marking (Note 5)

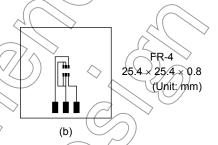


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s)

(b) Device mounted on a glass-epoxy board (b) (t = 5 s)





Note 3: $V_{DD} = -24 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.2 mH, $R_G = 25 \Omega$, $I_{AR} = -2.25 \text{ A}$

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: • to the lower left of the Part No. marking indicates Pin 1.

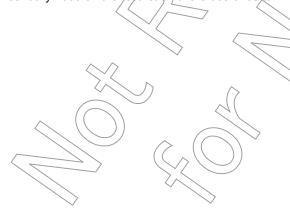
Note 6 A dot marking identifies the indication of product Labels.

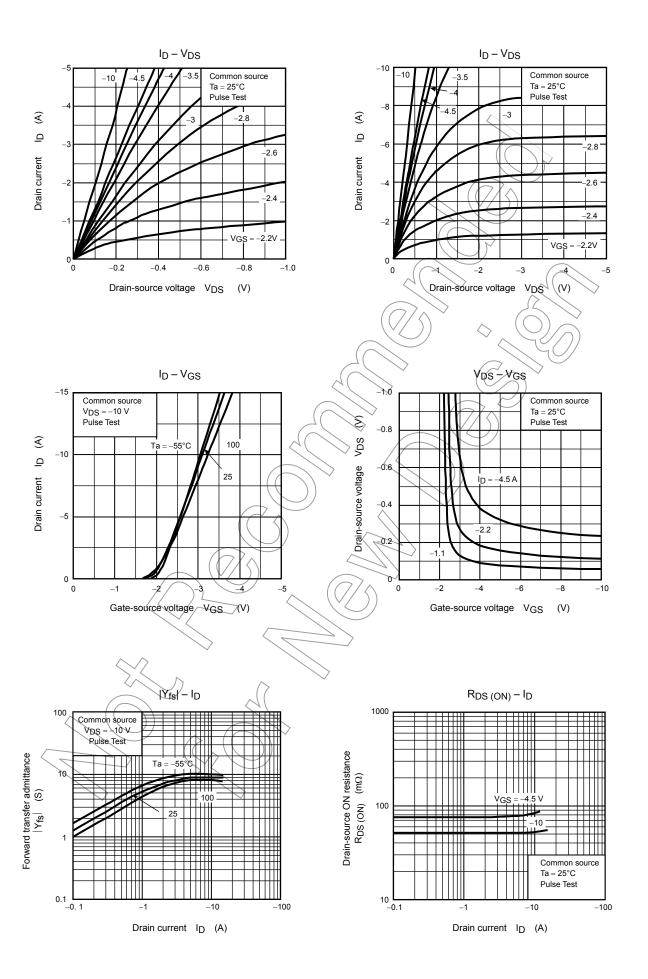
Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

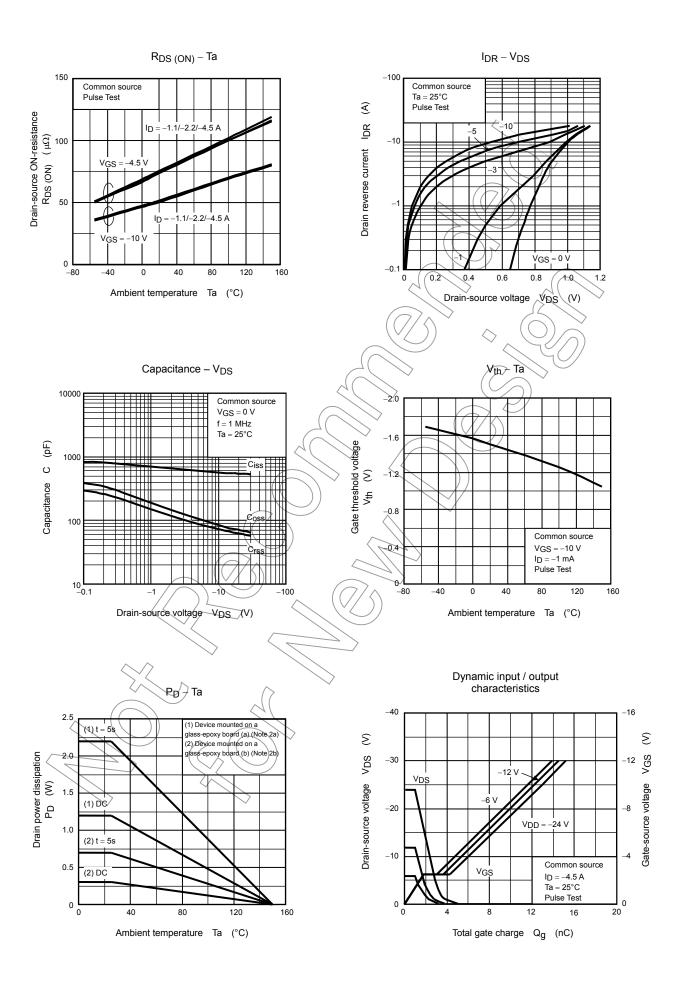
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

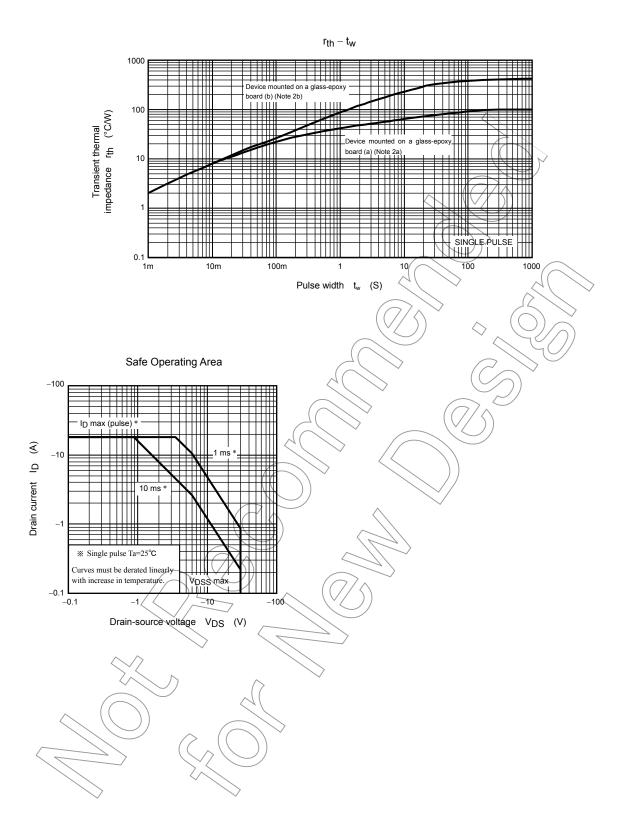
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